NSN 5961-01-160-2933

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Inclosure Material:

Metal

Overall Length:

1.563 inches

Overall Height:

0.350 inches

Overall Width:

1.050 inches

End Application:

1560-k0-158-032a

Mounting Facility Quantity:

2

Internal Configuration:

Field effect-dual gate

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

Current Rating Per Characteristic:

8.00 amperes source cutoff current of standard range and 20.00 amperes forward current, average any acceptable

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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